1 Ω Typical On Resistance, ±5 V, +12 V, +5 V, and +3.3 V Quad SPST Switches

Data Sheet **ADG1611/ADG1612/ADG1613**

FEATURES

- 1 Ω typical on resistance
- 0.2 Ω on resistance flatness
- ±3.3 V to ±8 V dual-supply operation
- 3.3 V to 16 V single-supply operation
- No V_L supply required
- 3 V logic-compatible inputs
- Rail-to-rail operation
- Continuous current per channel
  - LFCSP package: 280 mA
  - TSSOP package: 175 mA
- 16-lead TSSOP and 16-lead, 4 mm × 4 mm LFCSP

APPLICATIONS

- Communication systems
- Medical systems
- Audio signal routing
- Video signal routing
- Automatic test equipment
- Data acquisition systems
- Battery-powered systems
- Sample-and-hold systems
- Relay replacements

GENERAL DESCRIPTION

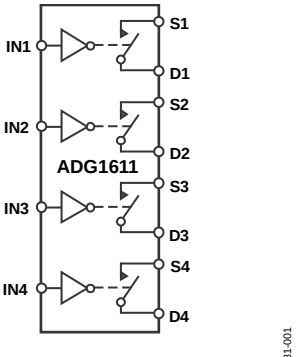
The ADG1611/ADG1612/ADG1613 contain four independent single-pole/single-throw (SPST) switches. The ADG1611 and ADG1612 differ only in that the digital control logic is inverted. The ADG1611 switches are turned on with Logic 0 on the appropriate control input, while Logic 1 is required for the ADG1612 switches. The ADG1613 has two switches with digital control logic similar to that of the ADG1611; the logic is inverted on the other two switches. Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked.

The ADG1613 exhibits break-before-make switching action for use in multiplexer applications. Inherent in the design is the low charge injection for minimum transients when switching the digital inputs.

The ultralow on resistance of these switches make them ideal solutions for data acquisition and gain switching applications where low on resistance and distortion is critical. The on resistance profile is very flat over the full analog input range, ensuring excellent linearity and low distortion when switching audio signals.

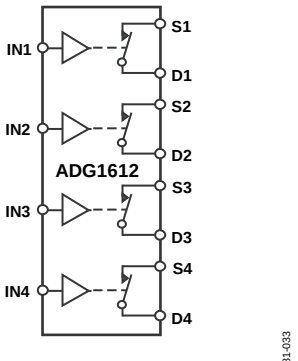
The CMOS construction ensures ultralow power dissipation, making them ideally suited for portable and battery-powered instruments.

FUNCTIONAL BLOCK DIAGRAMS



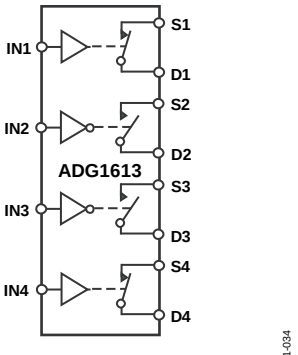
NOTES
1. SWITCHES SHOWN FOR A LOGIC 1 INPUT.

Figure 1.



NOTES
1. SWITCHES SHOWN FOR A LOGIC 1 INPUT.

Figure 2.



NOTES
1. SWITCHES SHOWN FOR A LOGIC 1 INPUT.

Figure 3.

PRODUCT HIGHLIGHTS

1. 1.6 Ω maximum on resistance over temperature.
2. Minimum distortion: THD + N = 0.007%.
3. 3 V logic-compatible digital inputs: V_{INH} = 2.0 V, V_{INL} = 0.8 V.
4. No V_L logic power supply required.
5. Ultralow power dissipation: <16 nW.
6. 16-lead TSSOP and 16-lead, 4 mm × 4 mm LFCSP.

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REVISION HISTORY

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Changed NC Pin to NIC Pin ... Throughout
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3/12—Rev. A to Rev. B

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8/09—Rev. 0 to Rev. A

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1/09—Revision 0: Initial Version

SPECIFICATIONS

±5 V DUAL SUPPLY

V_{DD} = +5 V ± 10%, V_{SS} = −5 V ± 10%, GND = 0 V, unless otherwise noted.

Table 1.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V_{DD} to V_{SS}	V	
On Resistance (R_{ON})	1			Ω typ	V_S = ±4.5 V, I_S = −10 mA; see Figure 24
	1.2	1.4	1.6	Ω max	V_{DD} = ±4.5 V, V_{SS} = ±4.5 V
On Resistance Match Between Channels (ΔR_{ON})	0.04			Ω typ	V_S = ±4.5 V, I_S = −10 mA
	0.08	0.09	0.1	Ω max	
On Resistance Flatness ($R_{FLAT(ON)}$)	0.2			Ω typ	V_S = ±4.5 V, I_S = −10 mA
	0.25	0.29	0.34	Ω max	
LEAKAGE CURRENTS					V_{DD} = +5.5 V, V_{SS} = −5.5 V
Source Off Leakage, I_S (Off)	±0.1			nA typ	V_S = ±4.5 V, V_D = ∓4.5 V; see Figure 25
	±0.3	±1	±6	nA max	
Drain Off Leakage, I_D (Off)	±0.1			nA typ	V_S = ±4.5 V, V_D = ∓4.5 V; see Figure 25
	±0.3	±1	±6	nA max	
Channel On Leakage, I_D, I_S (On)	±0.2			nA typ	V_S = V_D = ±4.5 V; see Figure 26
	±0.4	±1.5	±10	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	+0.005		±0.1	μA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	μA max	
Digital Input Capacitance, C_{IN}	5			pF typ	
DYNAMIC CHARACTERISTICS[1]					
t_{ON}	165			ns typ	R_L = 300 Ω, C_L = 35 pF
	212	253	285	ns max	V_S = 2.5 V; see Figure 31
t_{OFF}	105			ns typ	R_L = 300 Ω, C_L = 35 pF
	137	150	159	ns max	V_S = 2.5 V; see Figure 31
Break-Before-Make Time Delay, t_D (ADG1613 Only)	25			ns typ	R_L = 300 Ω, C_L = 35 pF
			20	ns min	V_{S1} = V_{S2} = 2.5 V; see Figure 32
Charge Injection	140			pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 1 nF; see Figure 33
Off Isolation	70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 27
Channel-to-Channel Crosstalk	110			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 28
Total Harmonic Distortion + Noise (THD + N)	0.007			% typ	R_L = 110 Ω, 5 V p-p, f = 20 Hz to 20 kHz; see Figure 30
−3 dB Bandwidth	42			MHz typ	R_L = 50 Ω, C_L = 5 pF; see Figure 29
C_S (Off)	63			pF typ	V_S = 0 V, f = 1 MHz
C_D (Off)	63			pF typ	V_S = 0 V, f = 1 MHz
C_D, C_S (On)	154			pF typ	V_S = 0 V, f = 1 MHz
POWER REQUIREMENTS					V_{DD} = +5.5 V, V_{SS} = −5.5 V
I_{DD}	0.001			μA typ	Digital inputs = 0 V or V_{DD}
			1.0	μA max	
V_{DD}/V_{SS}			±3.3/±8	V min/max	

[1] Guaranteed by design, not subject to production test.

12 V SINGLE SUPPLY

V_{DD} = 12 V ± 10%, V_{SS} = 0 V, GND = 0 V, unless otherwise noted.

Table 2.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V_{DD}	V	
On Resistance (R_{ON})	0.95			Ω typ	V_S = 0 V to 10 V, I_S = −10 mA; see Figure 24
	1.1	1.25	1.45	Ω max	V_{DD} = 10.8 V, V_{SS} = 0 V
On Resistance Match Between Channels (ΔR_{ON})	0.03			Ω typ	V_S = 0 V to 10 V, I_S = −10 mA
	0.06	0.7	0.08	Ω max	
On Resistance Flatness ($R_{FLAT(ON)}$)	0.2			Ω typ	V_S = 0 V to 10 V, I_S = −10 mA
	0.23	0.27	0.32	Ω max	
LEAKAGE CURRENTS					V_{DD} = 13.2 V, V_{SS} = 0 V
Source Off Leakage, I_S (Off)	±0.1			nA typ	V_S = 1 V/10 V, V_S = 10 V/1 V, see Figure 25
	±0.3	±1	±6	nA max	
Drain Off Leakage, I_D (Off)	±0.1			nA typ	V_S = 1 V/10 V, V_S = 10 V/1 V see Figure 25
	±0.3	±1	±6	nA max	
Channel On Leakage, I_D, I_S (On)	±0.2			nA typ	V_S = V_D = 1 V or 10 V; see Figure 26
	±0.4	±1.5	±10	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	0.001			μA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	μA max	
Digital Input Capacitance, C_{IN}	5			pF typ	
DYNAMIC CHARACTERISTICS[1]					
t_{ON}	125			ns typ	R_L = 300 Ω, C_L = 35 pF
	156	190	215	ns max	V_S = 8 V; see Figure 31
t_{OFF}	75			ns typ	R_L = 300 Ω, C_L = 35 pF
	87	93	99	ns max	V_S = 8 V; see Figure 31
Break-Before-Make Time Delay, t_D (ADG1613 Only)	35			ns typ	R_L = 300 Ω, C_L = 35 pF
			30	ns min	V_{S1} = V_{S2} = 8 V; see Figure 32
Charge Injection	170			pC typ	V_S = 6 V, R_S = 0 Ω, C_L = 1 nF; see Figure 33
Off Isolation	70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 27
Channel-to-Channel Crosstalk	110			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 28
Total Harmonic Distortion + Noise	0.012			% typ	R_L = 110 Ω, 5 V p-p, f = 20 Hz to 20 kHz; see Figure 30
−3 dB Bandwidth	38			MHz typ	R_L = 50 Ω, C_L = 5 pF; see Figure 29
C_S (Off)	60			pF typ	V_S = 6 V, f = 1 MHz
C_D (Off)	60			pF typ	V_S = 6 V, f = 1 MHz
C_D, C_S (On)	154			pF typ	V_S = 6 V, f = 1 MHz
POWER REQUIREMENTS					V_{DD} = 12 V
I_{DD}	0.001			μA typ	Digital inputs = 0 V or V_{DD}
			1	μA max	
I_{DD}	320			μA typ	Digital inputs = 5 V
			480	μA max	
V_{DD}			3.3/16	V min/max	

[1] Guaranteed by design, not subject to production test.

5 V SINGLE SUPPLY

V_{DD} = 5 V ± 10%, V_{SS} = 0 V, GND = 0 V, unless otherwise noted.

Table 3.

Parameter	25°C	−40°C to +85°C	−40°C to 125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V_{DD}	V	
On Resistance (R_{ON})	1.7			Ω typ	V_S = 0 V to 4.5 V, I_S = −10 mA; see Figure 24
	2.15	2.4	2.7	Ω max	V_{DD} = 4.5 V, V_{SS} = 0 V
On Resistance Match Between Channels (ΔR_{ON})	0.05			Ω typ	V_S = 0 V to 4.5 V, I_S = −10 mA
	0.09	0.12	0.15	Ω max	
On Resistance Flatness ($R_{FLAT(ON)}$)	0.4			Ω typ	V_S = 0 V to 4.5 V, I_S = −10 mA
	0.53	0.55	0.6	Ω max	
LEAKAGE CURRENTS					V_{DD} = 5.5 V, V_{SS} = 0 V
Source Off Leakage, I_S (Off)	±0.05			nA typ	V_S = 1 V/4.5 V, V_D = 4.5 V/1 V; see Figure 25
	±0.3	±1	±6	nA max	
Drain Off Leakage, I_D (Off)	±0.05			nA typ	V_S = 1 V/4.5 V, V_D = 4.5 V/1 V; see Figure 25
	±0.3	±1	±6	nA max	
Channel On Leakage, I_D, I_S (On)	±0.15			nA typ	V_S = V_D = 1 V or 4.5 V; see Figure 26
	±0.4	±1.5	±10	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	0.001			μA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	μA max	
Digital Input Capacitance, C_{IN}	5			pF typ	
DYNAMIC CHARACTERISTICS[1]					
t_{ON}	215			ns typ	R_L = 300 Ω, C_L = 35 pF
	279	334	376	ns max	V_S = 2.5 V; see Figure 31
t_{OFF}	115			ns typ	R_L = 300 Ω, C_L = 35 pF
	150	169	180	ns max	V_S = 2.5 V; see Figure 31
Break-Before-Make Time Delay, t_D (ADG1613 Only)	35			ns typ	R_L = 300 Ω, C_L = 35 pF
			25	ns min	V_{S1} = V_{S2} = 2.5 V; see Figure 32
Charge Injection	80			pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 1 nF; see Figure 33
Off Isolation	70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 100 kHz; see Figure 27
Channel-to-Channel Crosstalk	110			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 100 kHz; see Figure 28
Total Harmonic Distortion + Noise	0.093			% typ	R_L = 110 Ω, f = 20 Hz to 20 kHz, V_S = 3.5 V p-p; see Figure 30
−3 dB Bandwidth	42			MHz typ	R_L = 50 Ω, C_L = 5 pF; see Figure 29
C_S (Off)	72			pF typ	V_S = 2.5 V, f = 1 MHz
C_D (Off)	72			pF typ	V_S = 2.5 V, f = 1 MHz
C_D, C_S (On)	160			pF typ	V_S = 2.5 V, f = 1 MHz
POWER REQUIREMENTS					V_{DD} = 5.5 V
I_{DD}	0.001			μA typ	Digital inputs = 0 V or V_{DD}
			1	μA max	
V_{DD}			3.3/16	V min/max	

[1] Guaranteed by design, not subject to production test.

3.3 V SINGLE SUPPLY

V_{DD} = 3.3 V, V_{SS} = 0 V, GND = 0 V, unless otherwise noted.

Table 4.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V_{DD}	V	
On Resistance (R_{ON})	3.2	3.4	3.6	Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA, V_{DD} = 3.3 V, V_{SS} = 0 V; see Figure 24
On Resistance Match Between Channels (ΔR_{ON})	0.06	0.07	0.08	Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA
On Resistance Flatness ($R_{FLAT(ON)}$)	1.2	1.3	1.4	Ω typ	V_S = 0 V to V_{DD}, I_S = −10 mA
LEAKAGE CURRENTS					V_{DD} = 3.6 V, V_{SS} = 0 V
Source Off Leakage, I_S (Off)	±0.02			nA typ	V_S = 0.6 V/3 V, V_D = 3 V/0.6 V; see Figure 25
	±0.3	±1	±6	nA max	
Drain Off Leakage, I_D (Off)	±0.02			nA typ	V_S = 0.6 V/3 V, V_D = 3 V/0.6 V; see Figure 25
	±0.3	±1	±6	nA max	
Channel On Leakage, I_D, I_S (On)	±0.1			nA typ	V_S = V_D = 0.6 V or 3 V; see Figure 26
	±0.4	±1.5	±10	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	0.001			μA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	μA max	
Digital Input Capacitance, C_{IN}	3			pF typ	
DYNAMIC CHARACTERISTICS[1]					
t_{ON}	350			ns typ	R_L = 300 Ω, C_L = 35 pF
	493	556	603	ns max	V_S = 1.5 V; see Figure 31
t_{OFF}	190			ns typ	R_L = 300 Ω, C_L = 35 pF
	263	286	300	ns max	V_S = 1.5 V; see Figure 31
Break-Before-Make Time Delay, t_D (ADG1613 Only)	25			ns typ	R_L = 300 Ω, C_L = 35 pF
			18	ns min	V_{S1} = V_{S2} = 1.5 V; see Figure 32
Charge Injection	50			pC typ	V_S = 1.5 V, R_S = 0 Ω, C_L = 1 nF; see Figure 33
Off Isolation	70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 100 kHz; see Figure 27
Channel-to-Channel Crosstalk	110			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 100 kHz; see Figure 28
Total Harmonic Distortion + Noise	0.18			% typ	R_L = 110 Ω, f = 20 Hz to 20 kHz, V_S = 2 V p-p; see Figure 30
−3 dB Bandwidth	52			MHz typ	R_L = 50 Ω, C_L = 5 pF; see Figure 29
C_S (Off)	76			pF typ	V_S = 1.5 V, f = 1 MHz
C_D (Off)	76			pF typ	V_S = 1.5 V, f = 1 MHz
C_D, C_S (On)	160			pF typ	V_S = 1.5 V, f = 1 MHz
POWER REQUIREMENTS					V_{DD} = 3.6 V
I_{DD}	0.001			μA typ	Digital inputs = 0 V or V_{DD}
		1.0	1.0	μA max	
V_{DD}			3.3/16	V min/max	

[1] Guaranteed by design, not subject to production test.

CONTINUOUS CURRENT PER CHANNEL, S OR D

Table 5.

Parameter	25°C	85°C	125°C	Unit
CONTINUOUS CURRENT, S OR D				
V_{DD} = +5 V, V_{SS} = −5 V				
TSSOP (θ_{JA} = 150.4°C/W)	175	119	70	mA maximum
LFCSP (θ_{JA} = 48.7°C/W)	280	175	95	mA maximum
V_{DD} = 12 V, V_{SS} = 0 V				
TSSOP (θ_{JA} = 150.4°C/W)	206	135	84	mA maximum
LFCSP (θ_{JA} = 48.7°C/W)	336	203	108	mA maximum
V_{DD} = 5 V, V_{SS} = 0 V				
TSSOP (θ_{JA} = 150.4°C/W)	140	91	63	mA maximum
LFCSP (θ_{JA} = 48.7°C/W)	220	140	84	mA maximum
V_{DD} = 3.3 V, V_{SS} = 0 V				
TSSOP (θ_{JA} = 150.4°C/W)	140	98	70	mA maximum
LFCSP (θ_{JA} = 48.7°C/W)	228	150	91	mA maximum

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 6.

Parameter	Rating
V_{DD} to V_{SS}	18 V
V_{DD} to GND	−0.3 V to +18 V
V_{SS} to GND	+0.3 V to −18 V
Analog Inputs[1]	V_{SS} − 0.3 V to V_{DD} + 0.3 V or 30 mA, whichever occurs first
Digital Inputs[1]	GND − 0.3 V to V_{DD} + 0.3 V or 30 mA, whichever occurs first
Peak Current, S or D	630 mA (pulsed at 1 ms, 10% duty-cycle maximum)
Continuous Current, S or D[2]	Data + 15%
Operating Temperature Range	
Industrial (Y Version)	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
16-Lead TSSOP, θ_{JA} Thermal Impedance (2-Layer Board)	150.4°C/W
16-Lead LFCSP, θ_{JA} Thermal Impedance (4-Layer Board)	48.7°C/W
Reflow Soldering Peak Temperature, Pb free	260°C

[1] Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.
[2] See Table 5.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

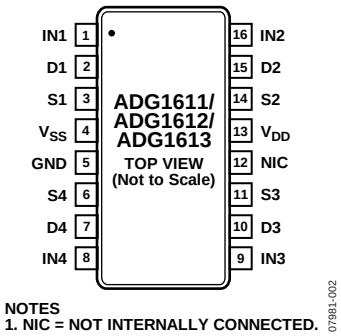


Figure 4. 16-Lead TSSOP Pin Configuration

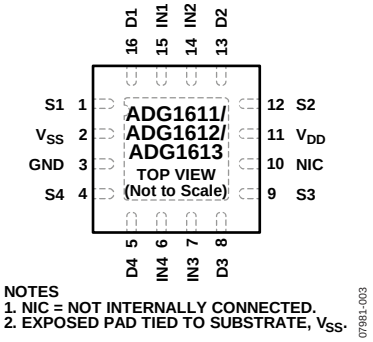


Figure 5. 16-Lead LFCSP Pin Configuration

Table 7. Pin Function Descriptions

Pin No.			
16-Lead TSSOP	**16-Lead LFCSP**	**Mnemonic**	**Description**
1	15	IN1	Logic Control Input.
2	16	D1	Drain Terminal. This pin can be an input or output.
3	1	S1	Source Terminal. This pin can be an input or output.
4	2	V_{SS}	Most Negative Power Supply Potential.
5	3	GND	Ground (0 V) Reference.
6	4	S4	Source Terminal. This pin can be an input or output.
7	5	D4	Drain Terminal. This pin can be an input or output.
8	6	IN4	Logic Control Input.
9	7	IN3	Logic Control Input.
10	8	D3	Drain Terminal. This pin can be an input or output.
11	9	S3	Source Terminal. This pin can be an input or output.
12	10	NIC	Not Internally Connected.
13	11	V_{DD}	Most Positive Power Supply Potential.
14	12	S2	Source Terminal. This pin can be an input or output.
15	13	D2	Drain Terminal. This pin can be an input or output.
16	14	IN2	Logic Control Input.
Not applicable	17 (EPAD)	EP (EPAD)	Exposed Pad. Tied to substrate, V_{SS}.

Table 8. ADG1611/ADG1612 Truth Table

ADG1611 INx	**ADG1612 INx**	**Switch Condition**
0	1	On
1	0	Off

Table 9. ADG1613 Truth Table

Logic (INx)	**Switch 1, Switch 4**	**Switch 2, Switch 3**
0	Off	On
1	On	Off

TYPICAL PERFORMANCE CHARACTERISTICS

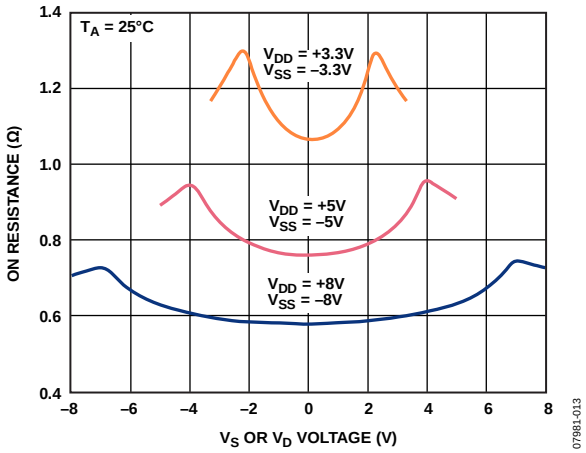


Figure 6. On Resistance as a Function of V_D (V_S) for Dual Supply

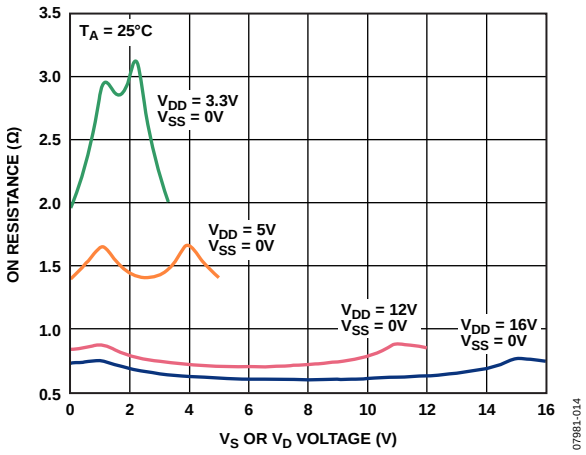


Figure 7. On Resistance as a Function of V_D (V_S) for Single Supply

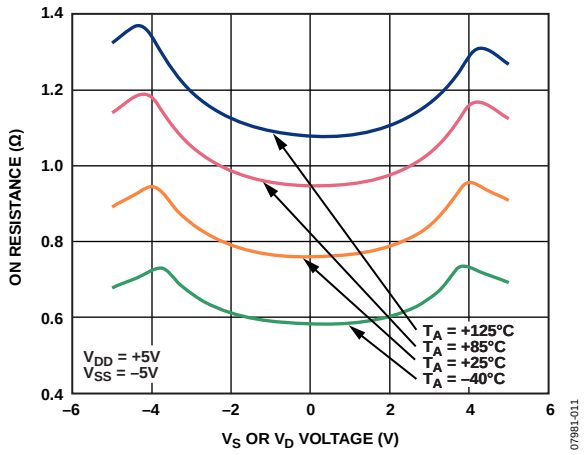


Figure 8. On Resistance as a Function of V_D (V_S) for Different Temperatures, ±5 V Dual Supply

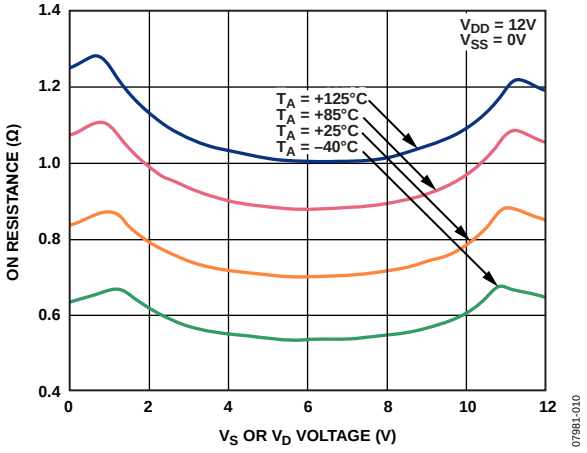


Figure 9. On Resistance as a Function of V_D (V_S) for Different Temperatures, 12 V Single Supply

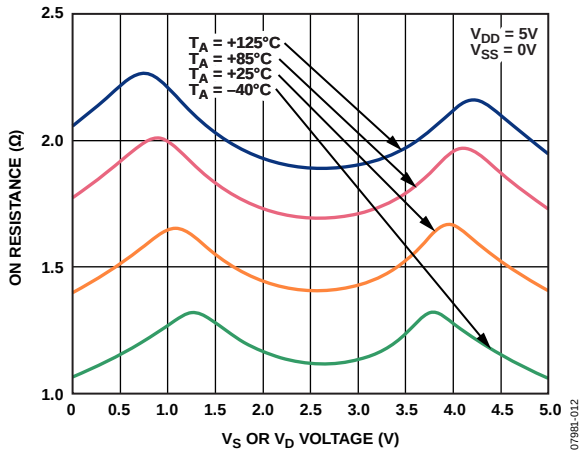


Figure 10. On Resistance as a Function of V_D (V_S) for Different Temperatures, 5 V Single Supply

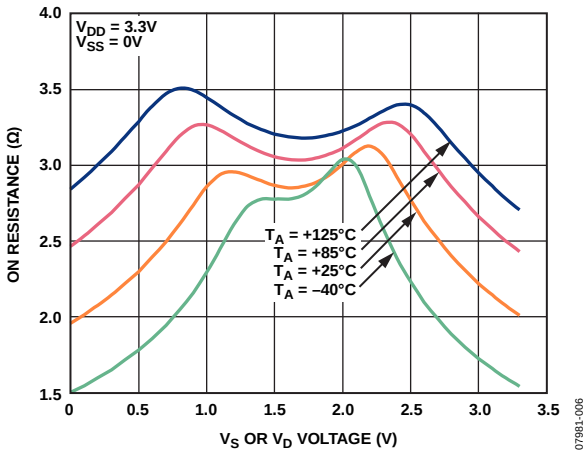


Figure 11. On Resistance as a Function of V_D (V_S) for Different Temperatures, 3.3 V Single Supply

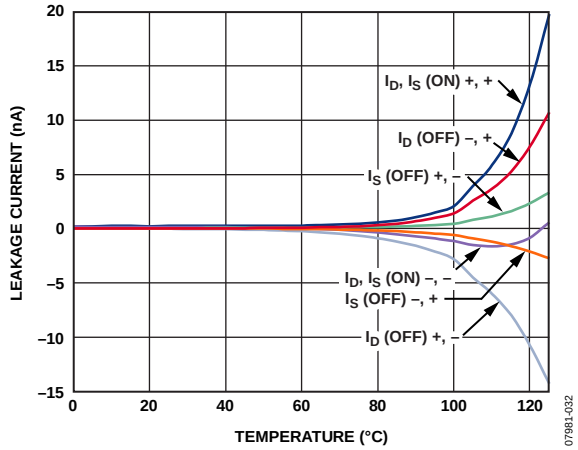


Figure 12. Leakage Currents as a Function of Temperature, ±5 V Dual Supply

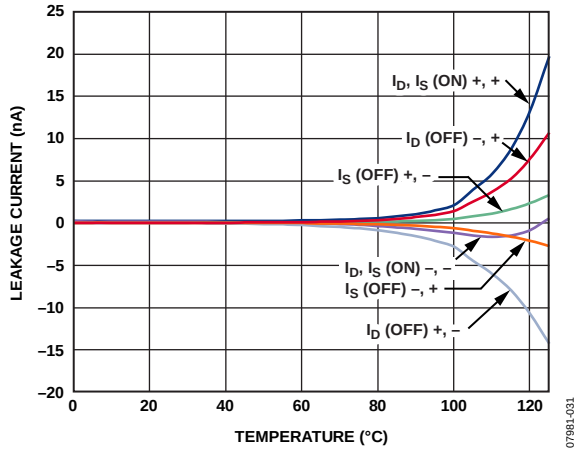


Figure 13. Leakage Currents as a Function of Temperature, 12 V Single Supply

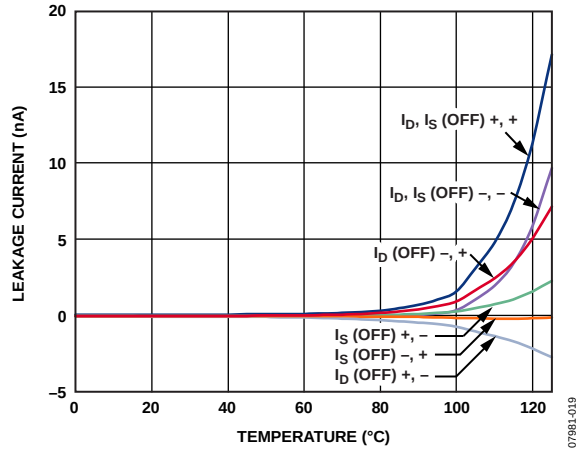


Figure 14. Leakage Currents as a Function of Temperature, 5 V Single Supply

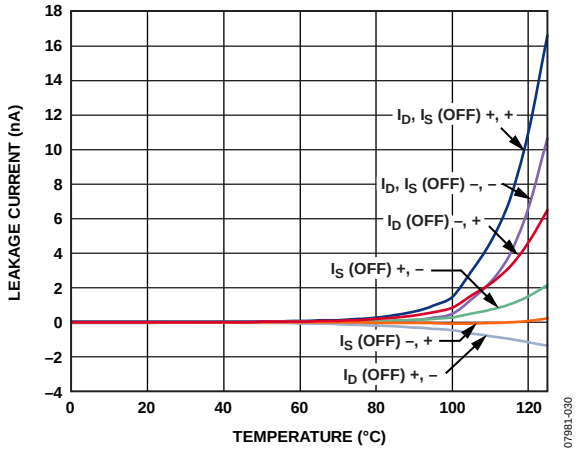


Figure 15. Leakage Currents as a Function of Temperature, 3.3 V Single Supply

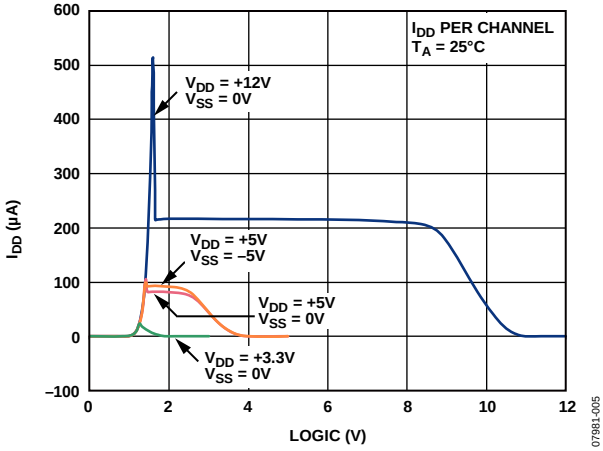


Figure 16. I_{DD} vs. Logic Level

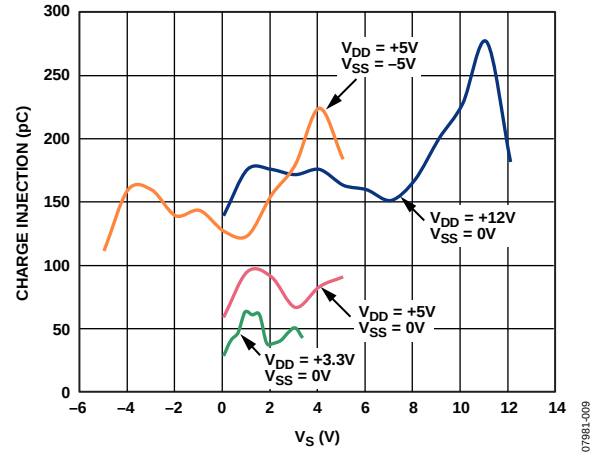


Figure 17. Charge Injection vs. Source Voltage (V_S)

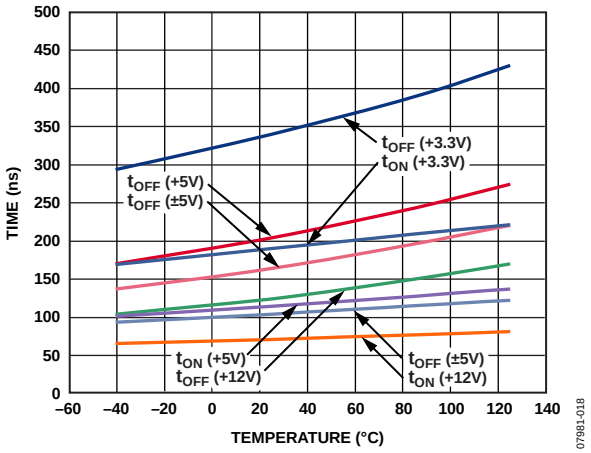


Figure 18. t_{ON}/t_{OFF} Times vs. Temperature

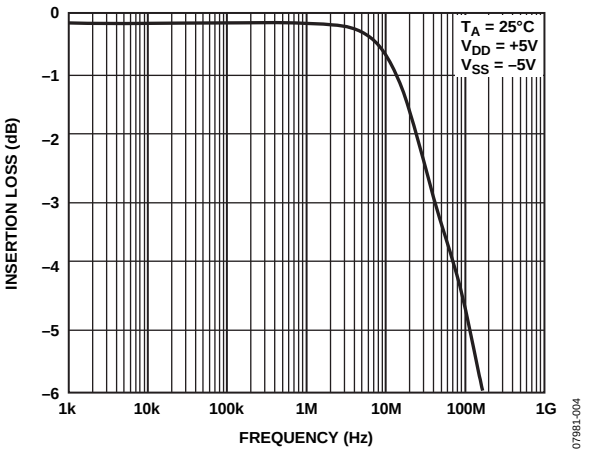


Figure 21. On Response vs. Frequency

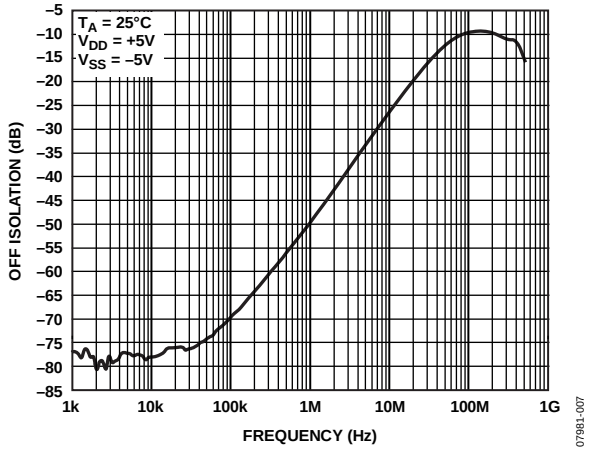


Figure 19. Off Isolation vs. Frequency

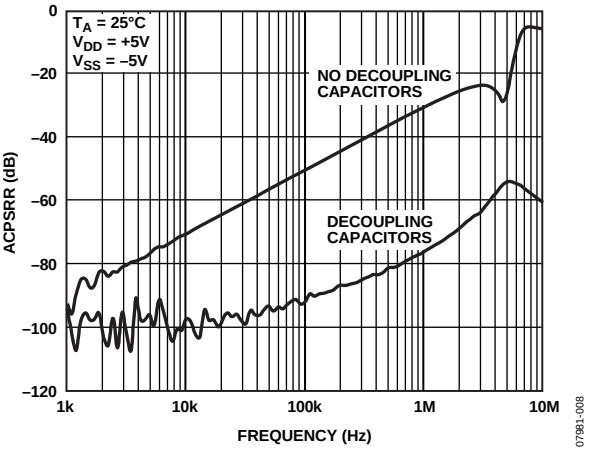


Figure 22. ACPSRR vs. Frequency

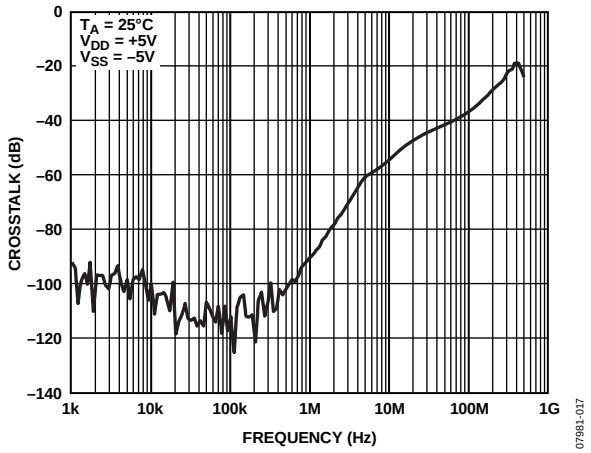


Figure 20. Crosstalk vs. Frequency

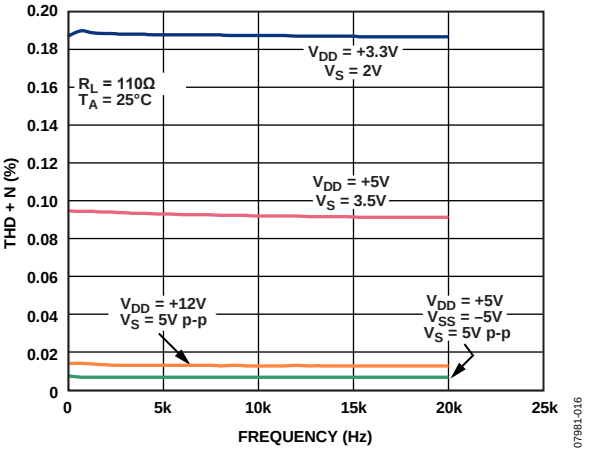


Figure 23. THD + N vs. Frequency

TEST CIRCUITS

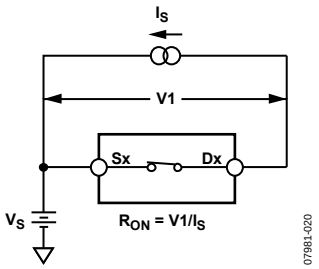


Figure 24. On Resistance

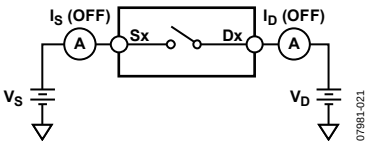


Figure 25. Off Leakage

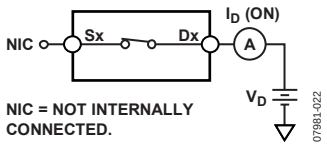


Figure 26. On Leakage

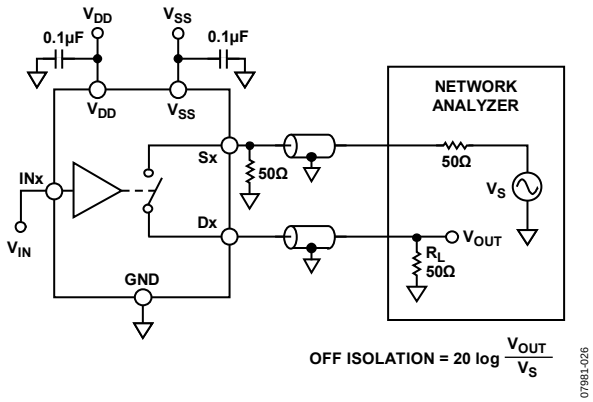


Figure 27. Off Isolation

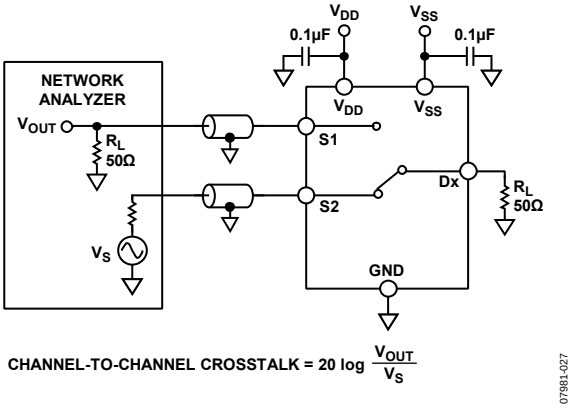


Figure 28. Channel-to-Channel Crosstalk

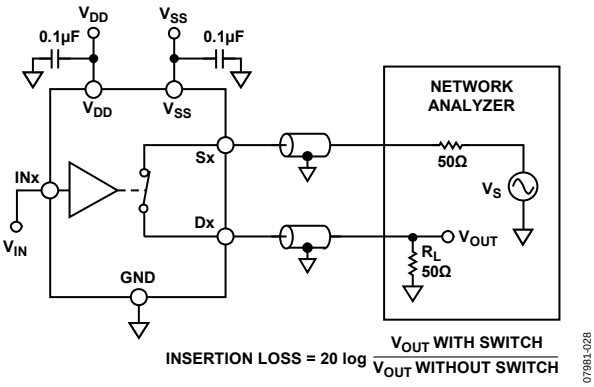


Figure 29. Bandwidth

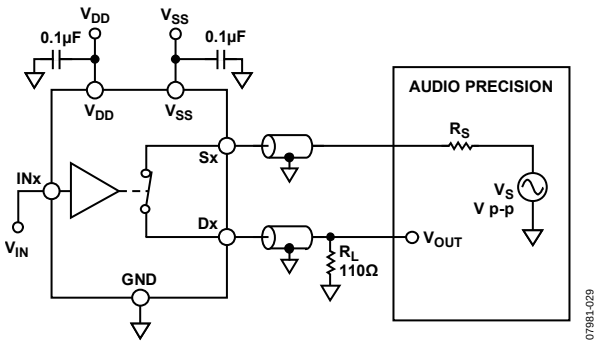


Figure 30. THD + Noise

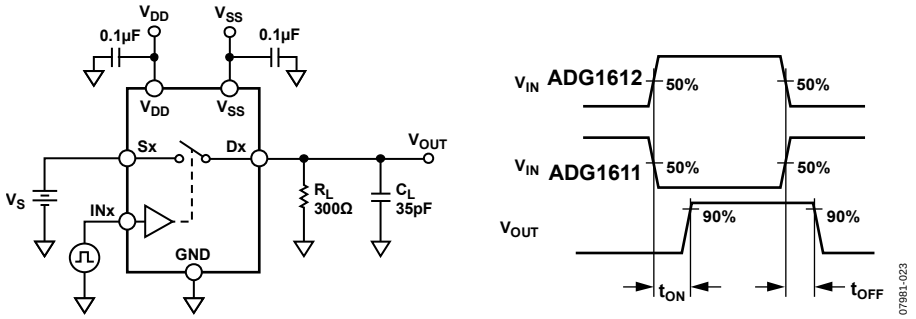


Figure 31. Switching Times

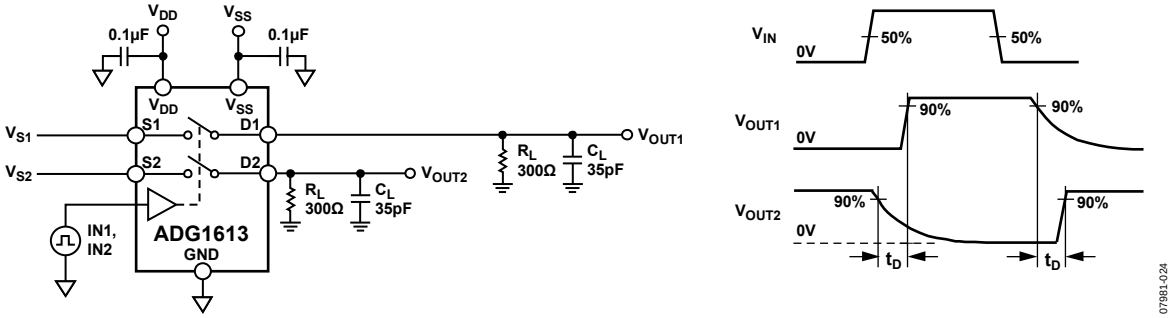


Figure 32. Break-Before-Make Time Delay

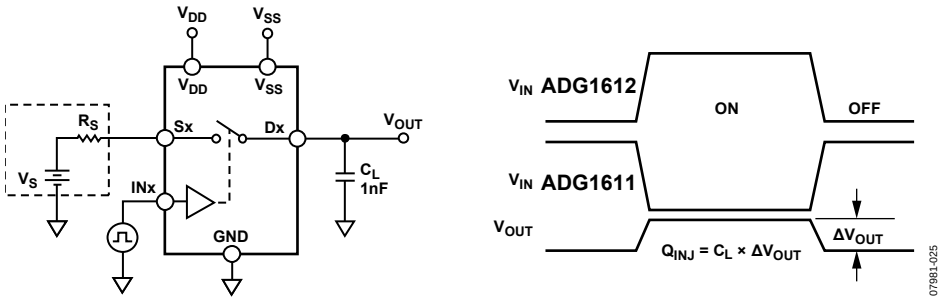


Figure 33. Charge Injection

TERMINOLOGY

I_{DD}
The positive supply current.

I_{SS}
The negative supply current.

V_D (V_S)
The analog voltage on Terminal D and Terminal S.

R_{ON}
The ohmic resistance between Terminal D and Terminal S.

$R_{FLAT(ON)}$
Flatness that is defined as the difference between the maximum and minimum value of on resistance measured over the specified analog signal range.

I_S (Off)
The source leakage current with the switch off.

I_D (Off)
The drain leakage current with the switch off.

I_D, I_S (On)
The channel leakage current with the switch on.

V_{INL}
The maximum input voltage for Logic 0.

V_{INH}
The minimum input voltage for Logic 1.

I_{INL} (I_{INH})
The input current of the digital input.

C_S (Off)
The off switch source capacitance, which is measured with reference to ground.

C_D (Off)
The off switch drain capacitance, which is measured with reference to ground.

C_D, C_S (On)
The on switch capacitance, which is measured with reference to ground.

C_{IN}
The digital input capacitance.

t_{ON}
The delay between applying the digital control input and the output switching on. See Figure 31.

t_{OFF}
The delay between applying the digital control input and the output switching off. See Figure 31.

Charge Injection
A measure of the glitch impulse transferred from the digital input to the analog output during switching. See Figure 33.

Off Isolation
A measure of unwanted signal coupling through an off switch. See Figure 27.

Crosstalk
A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance. See Figure 28.

Bandwidth
The frequency at which the output is attenuated by 3 dB. See Figure 29.

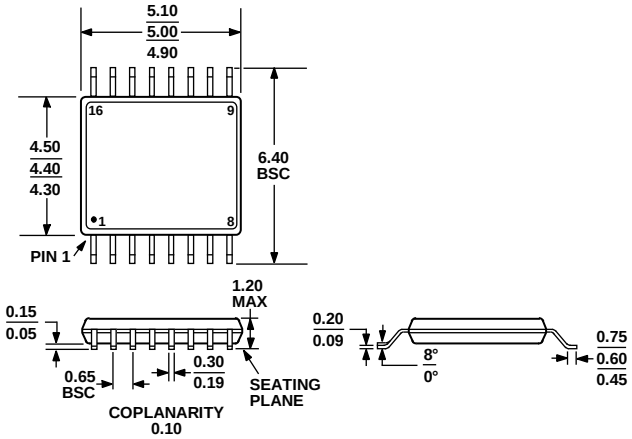
On Response
The frequency response of the on switch.

Insertion Loss
The loss due to the on resistance of the switch.

Total Harmonic Distortion + Noise (THD + N)
The ratio of the harmonic amplitude plus noise of the signal to the fundamental. See Figure 30.

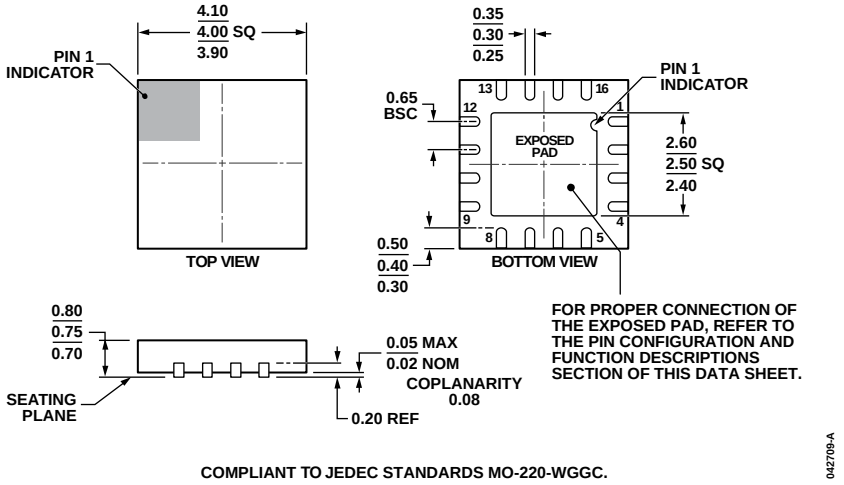
AC Power Supply Rejection Ratio (ACPSRR)
The ratio of the amplitude of signal on the output to the amplitude of the modulation. This is a measure of the ability of the part to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 34. 16-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-16)
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-220-WGGC.

Figure 35. 16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]
4 mm × 4 mm Body, Very Very Thin Quad
(CP-16-26)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option
ADG1611BRUZ	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1611BRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1611BRUZ-REEL7	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1611BCPZ-REEL	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-26
ADG1611BCPZ-REEL7	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-26
ADG1612BRUZ	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1612BRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1612BRUZ-REEL7	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1612BCPZ- REEL	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-26
ADG1612BCPZ-REEL7	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-26
ADG1613BRUZ	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1613BRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1613BRUZ-REEL7	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1613BCPZ-REEL	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-26
ADG1613BCPZ-REEL7	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-26

[1] Z = RoHS Compliant Part.

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